



"Dielectric Layer For A Semiconductor Device And
Method Of Producing The Same"
Serial. No. 10/638,424 – Attny. Doc. No. WLJ.068D
Inventor: John MACNEIL

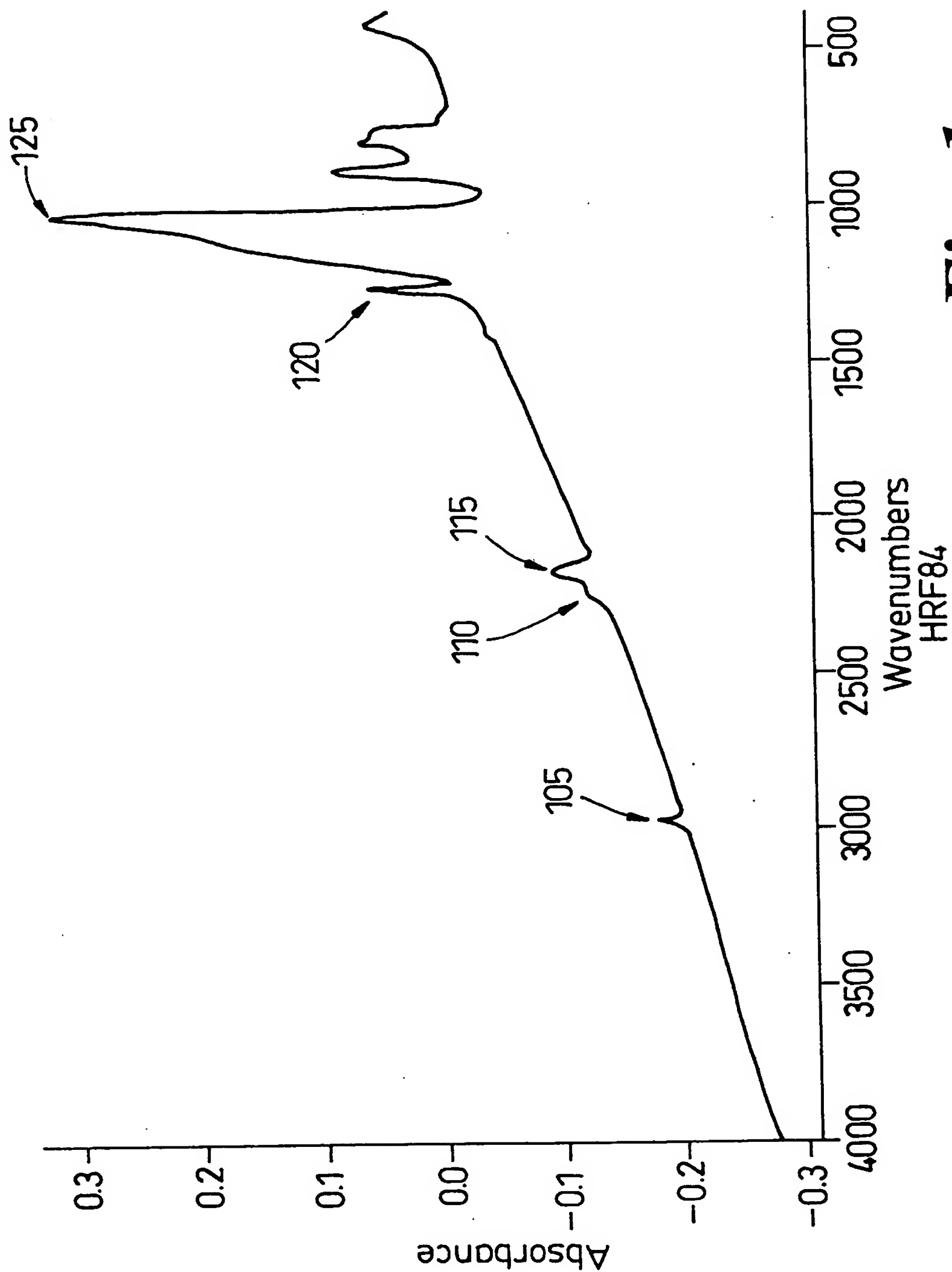


Fig. 1



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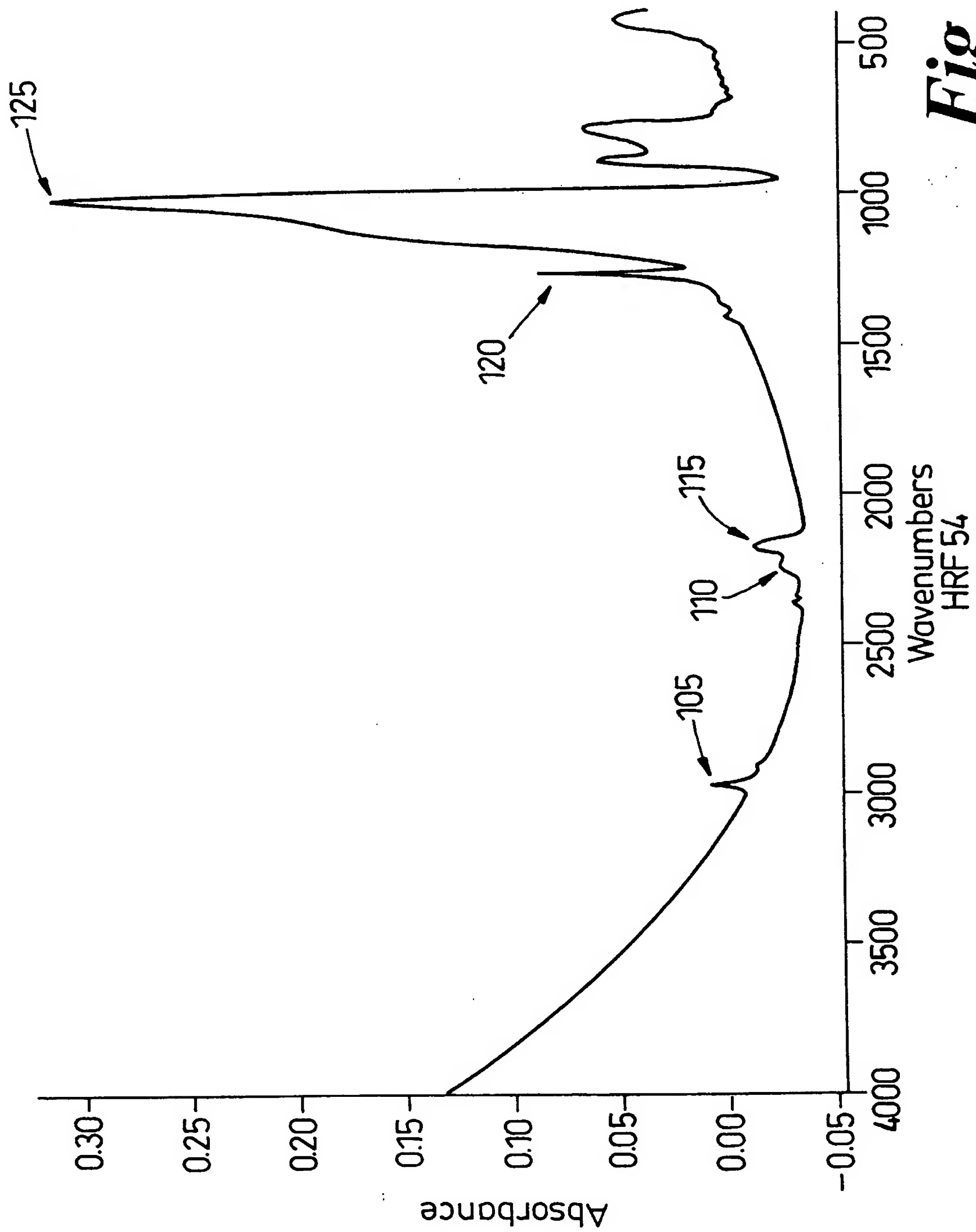


Fig 2



"Dielectric Layer For A Semiconductor Device And
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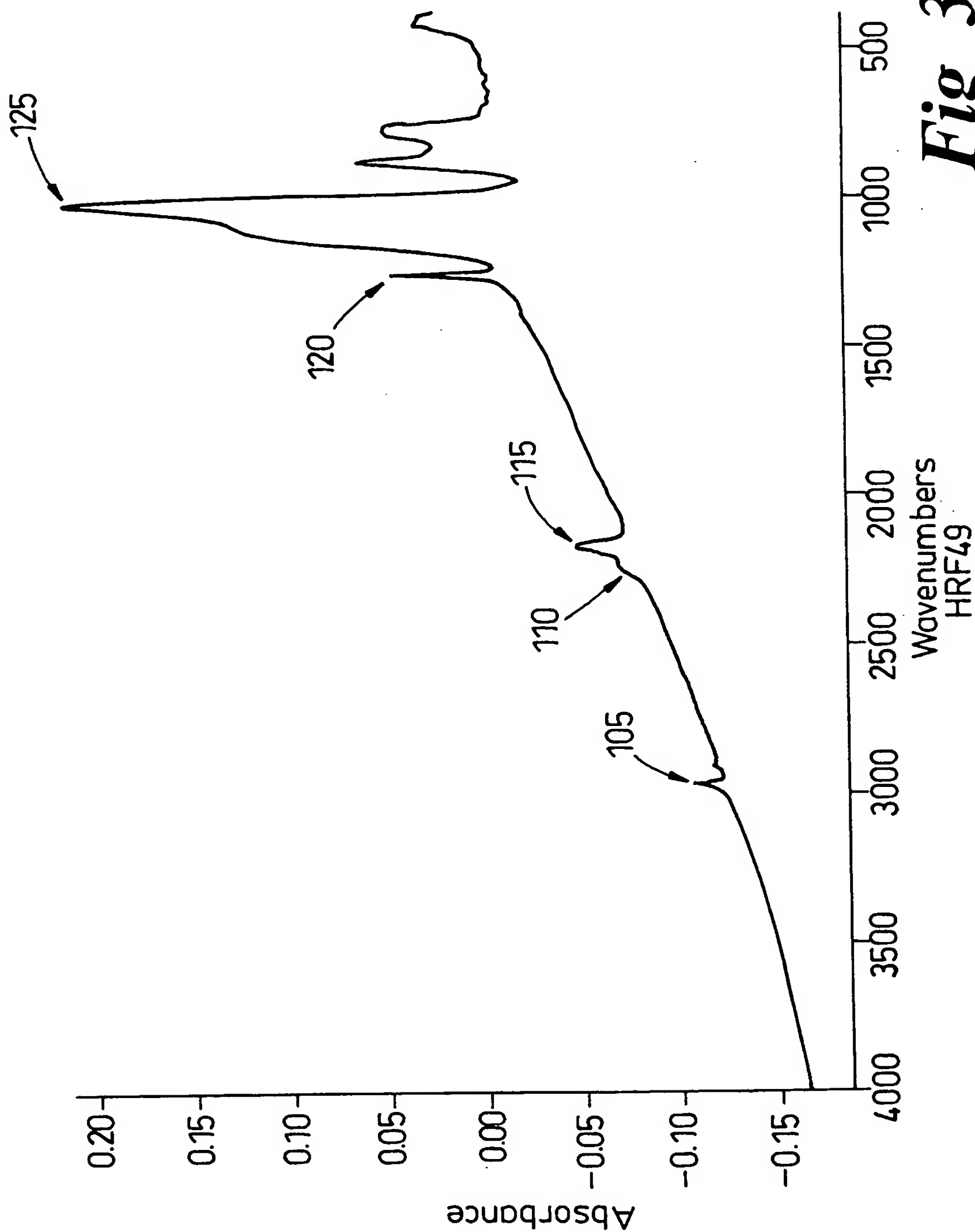


Fig 3

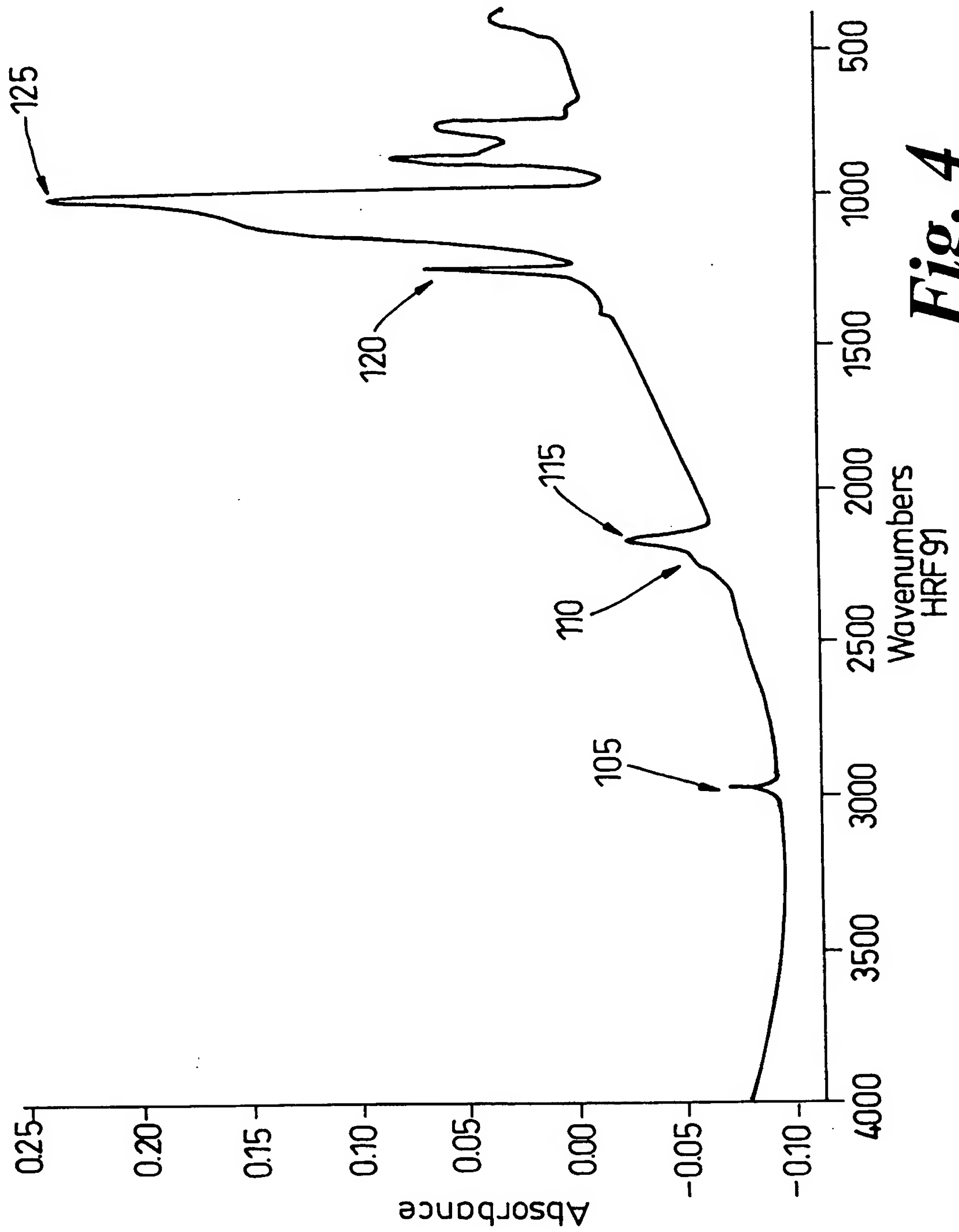


Fig. 4

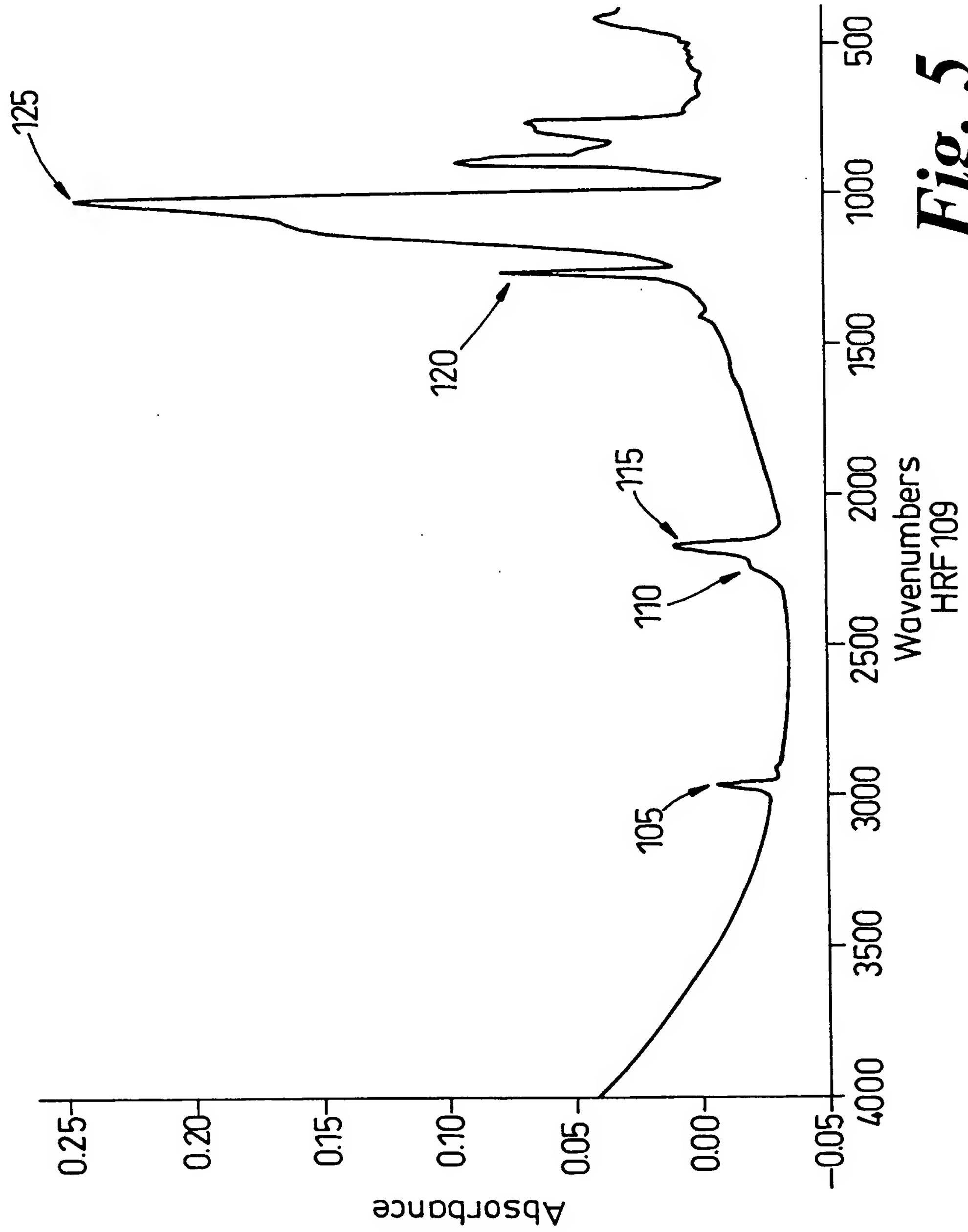


Fig. 5

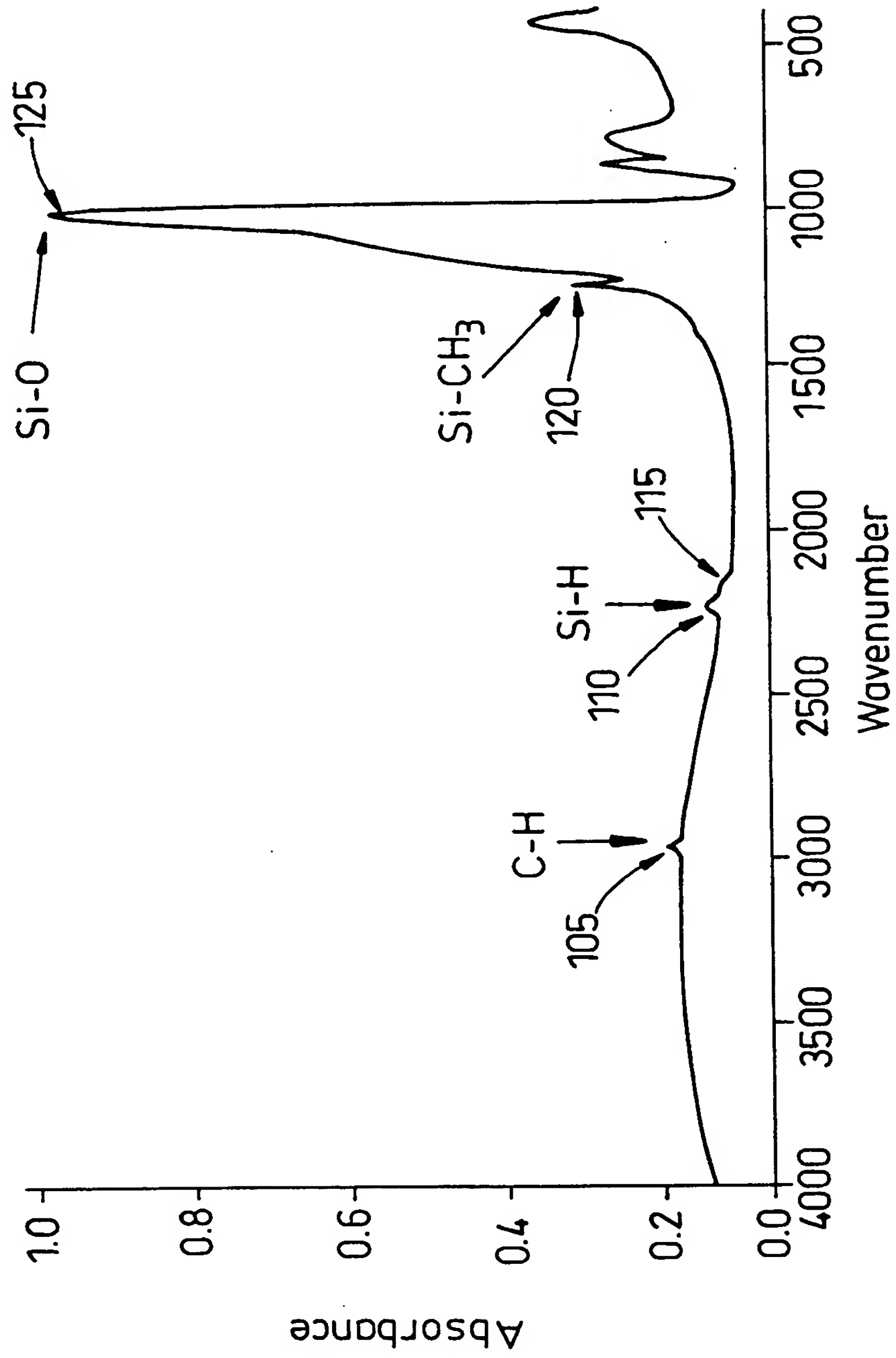


Fig. 6

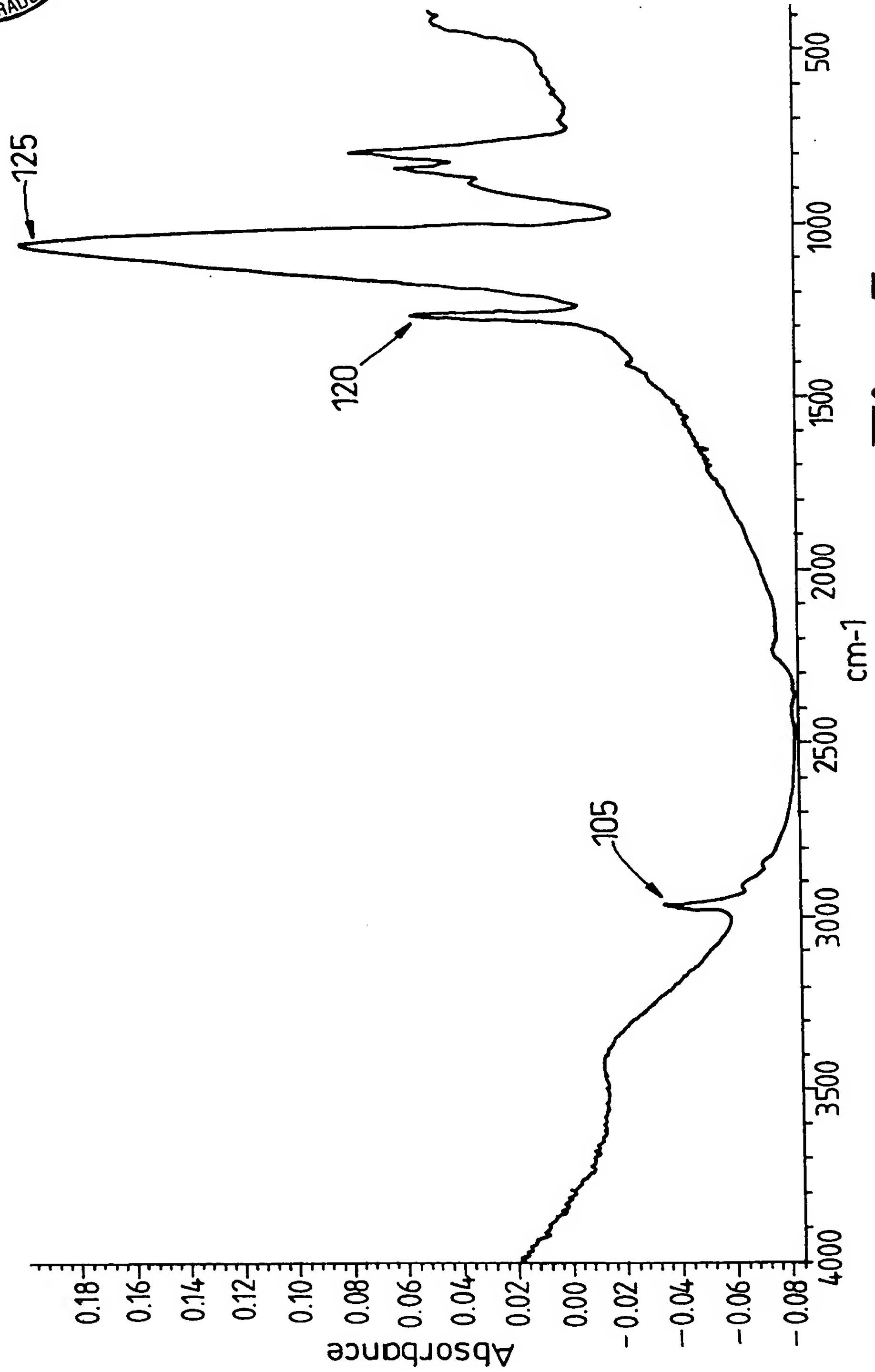


Fig. 7

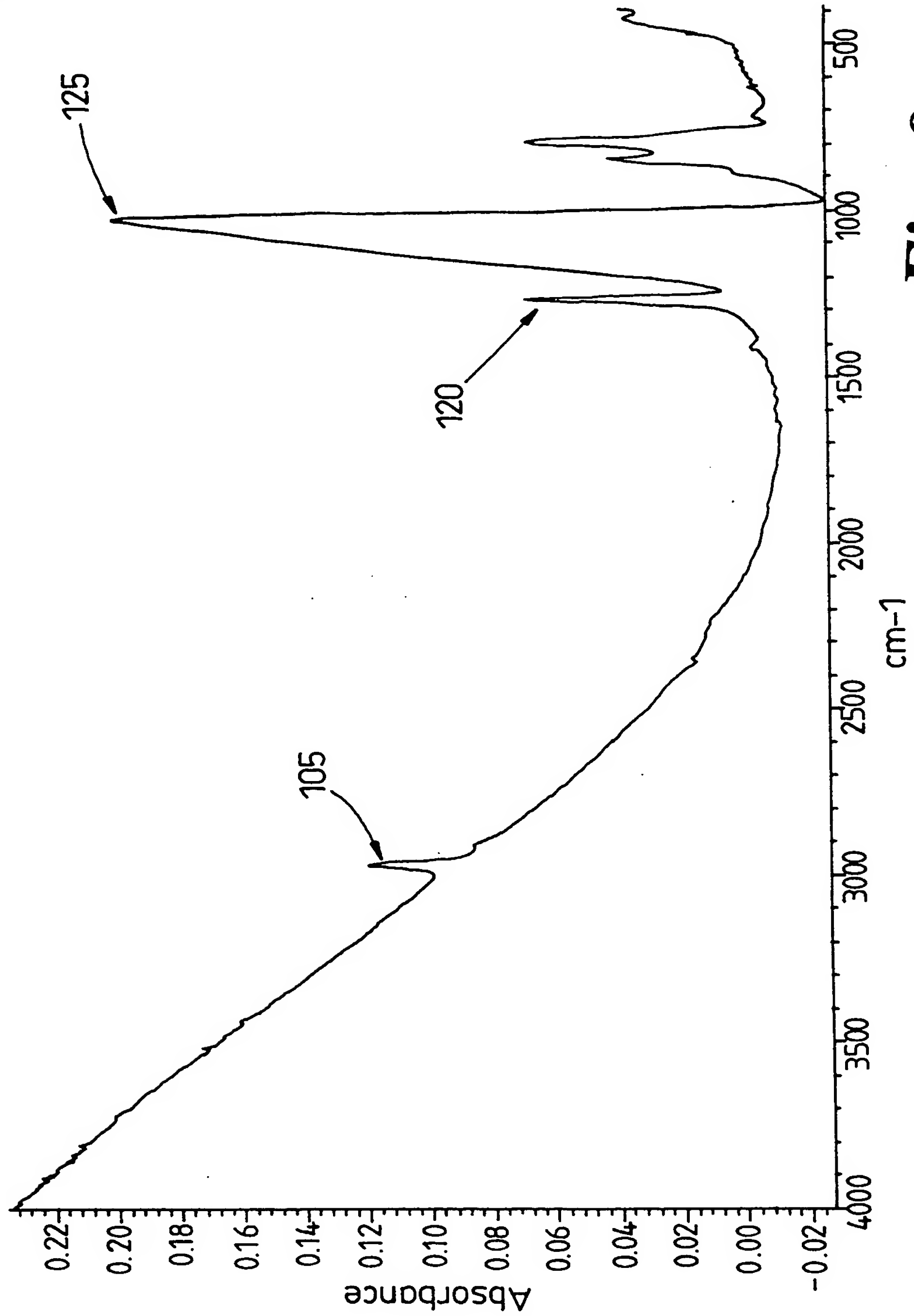


Fig. 8

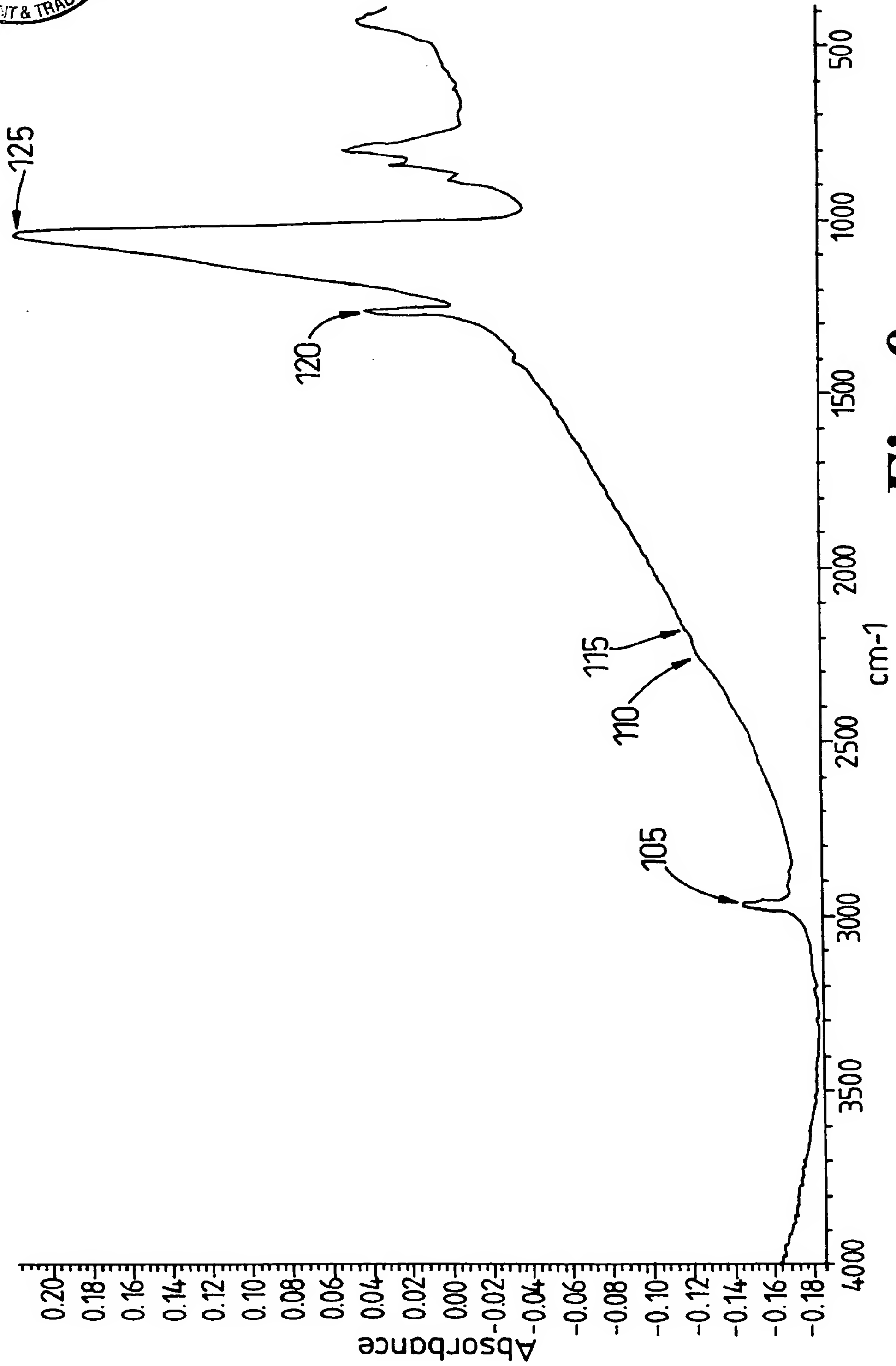


Fig. 9

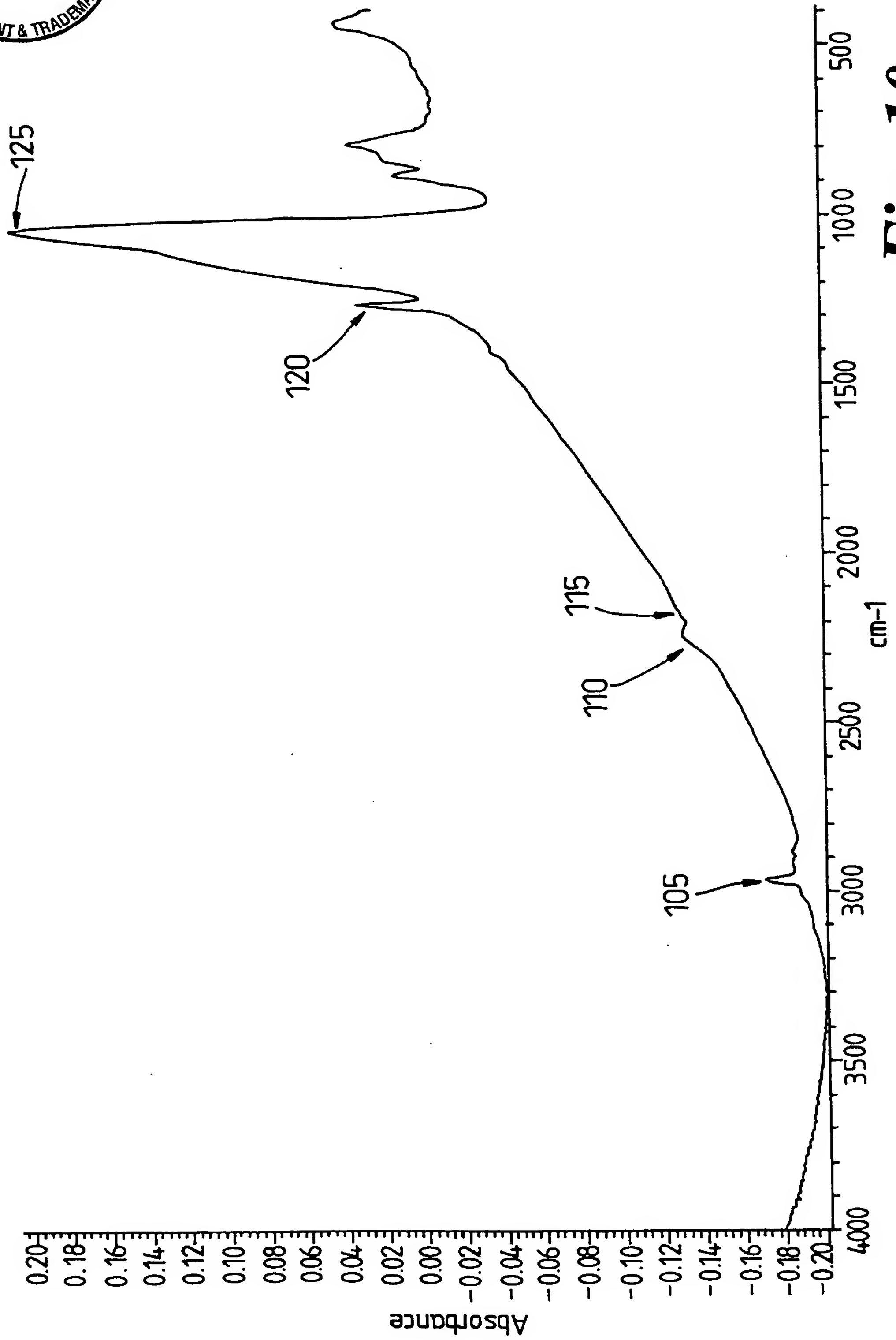


Fig. 10

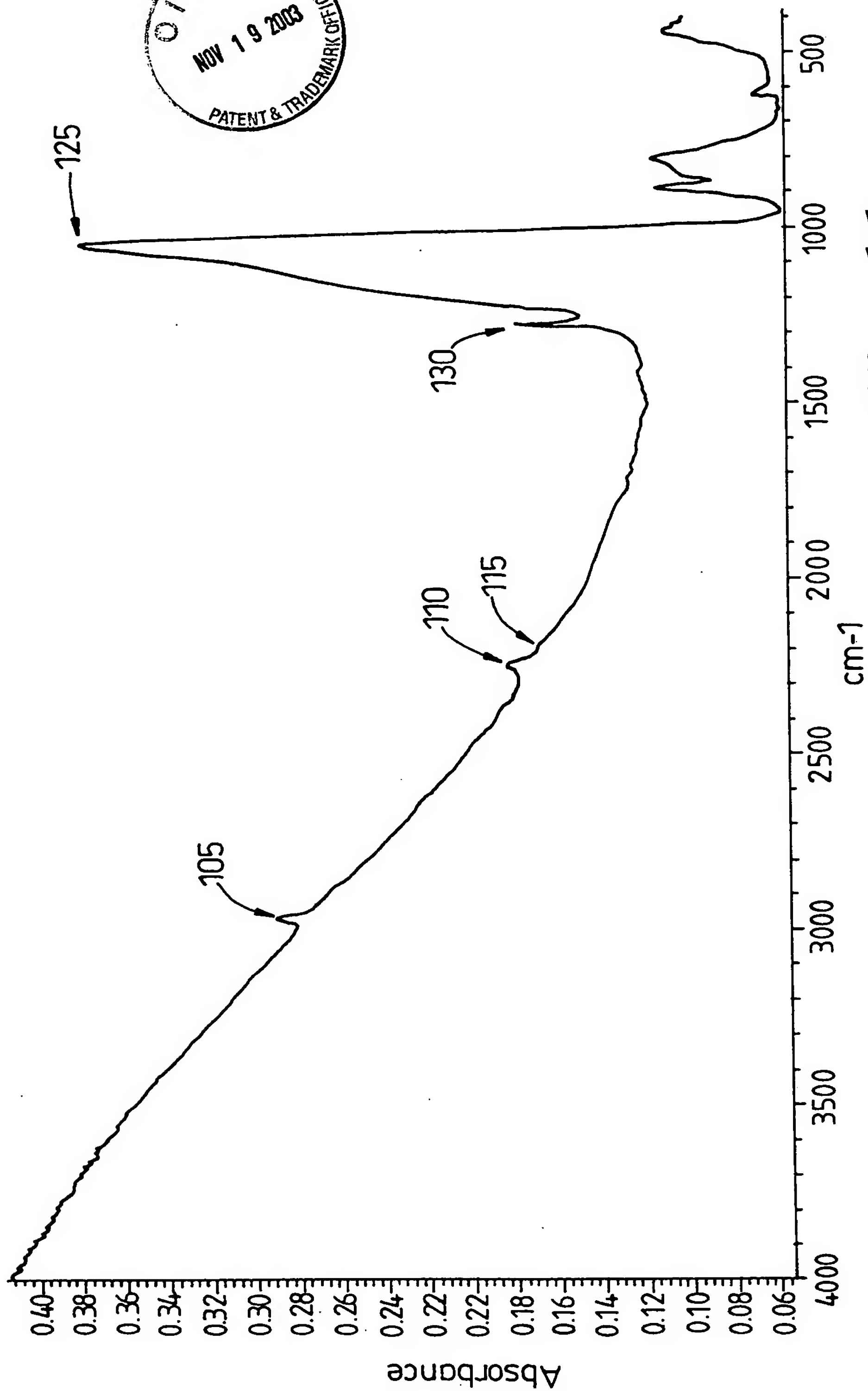


Fig. 11

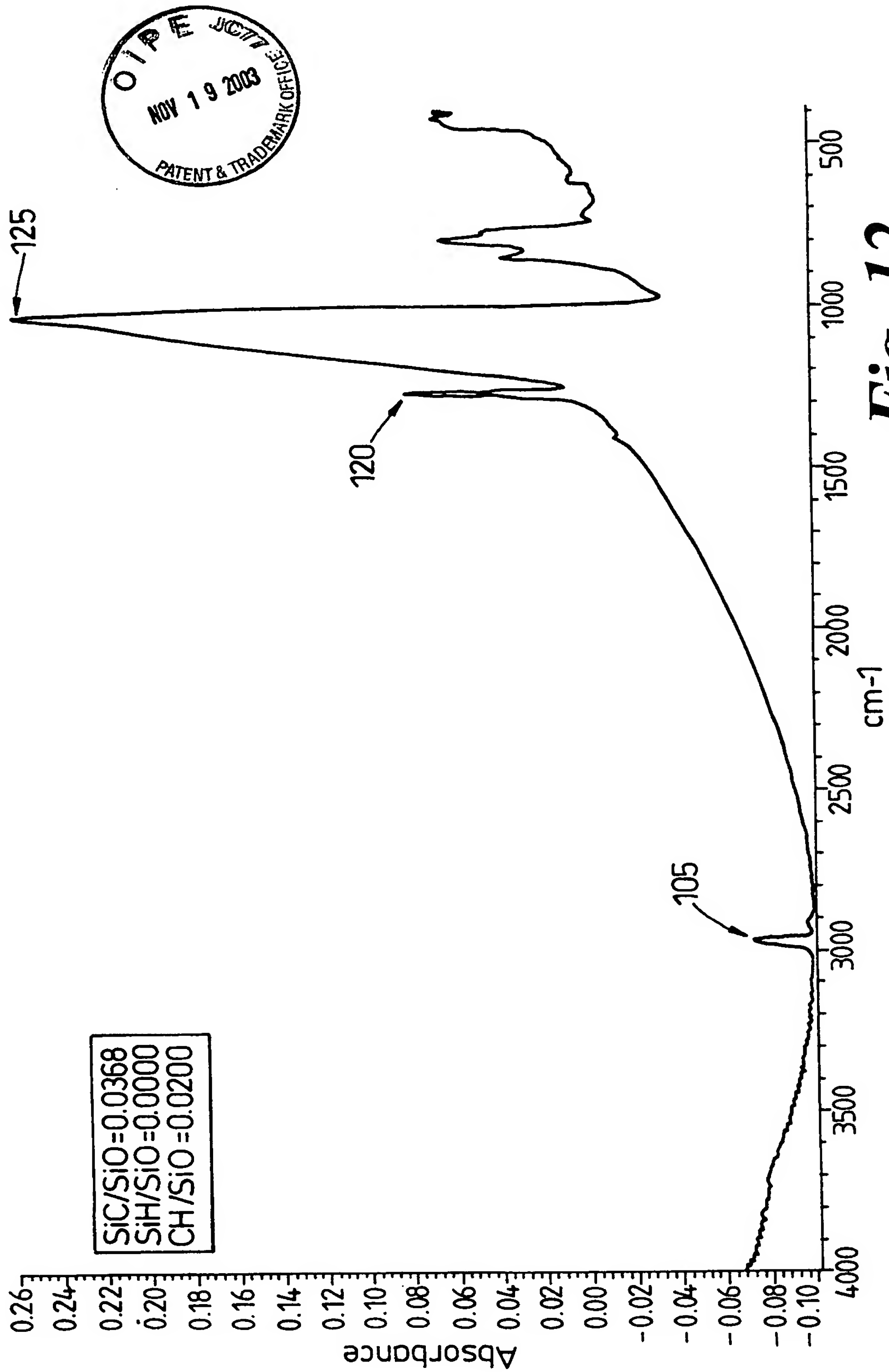


Fig 12

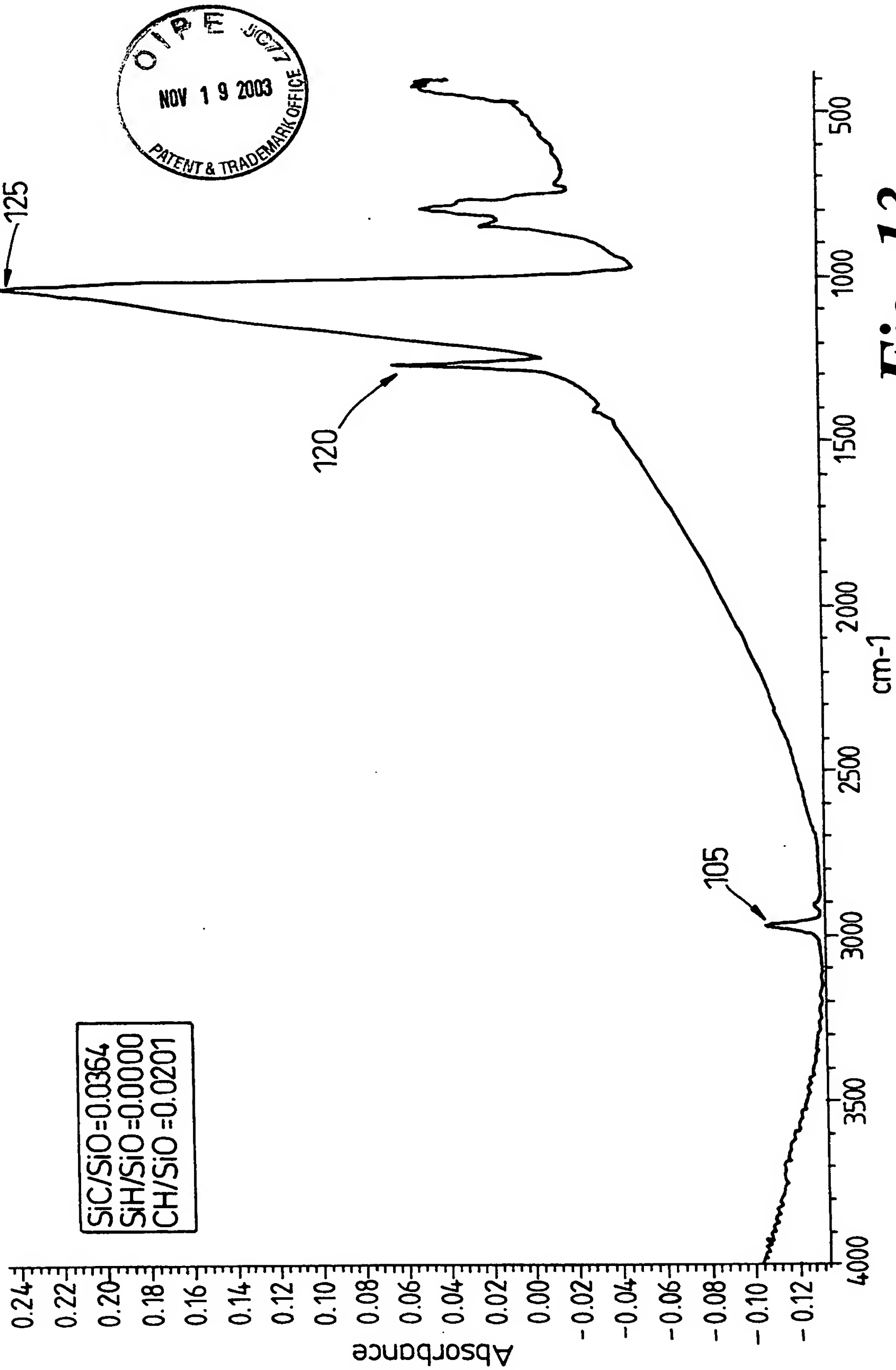


Fig 13

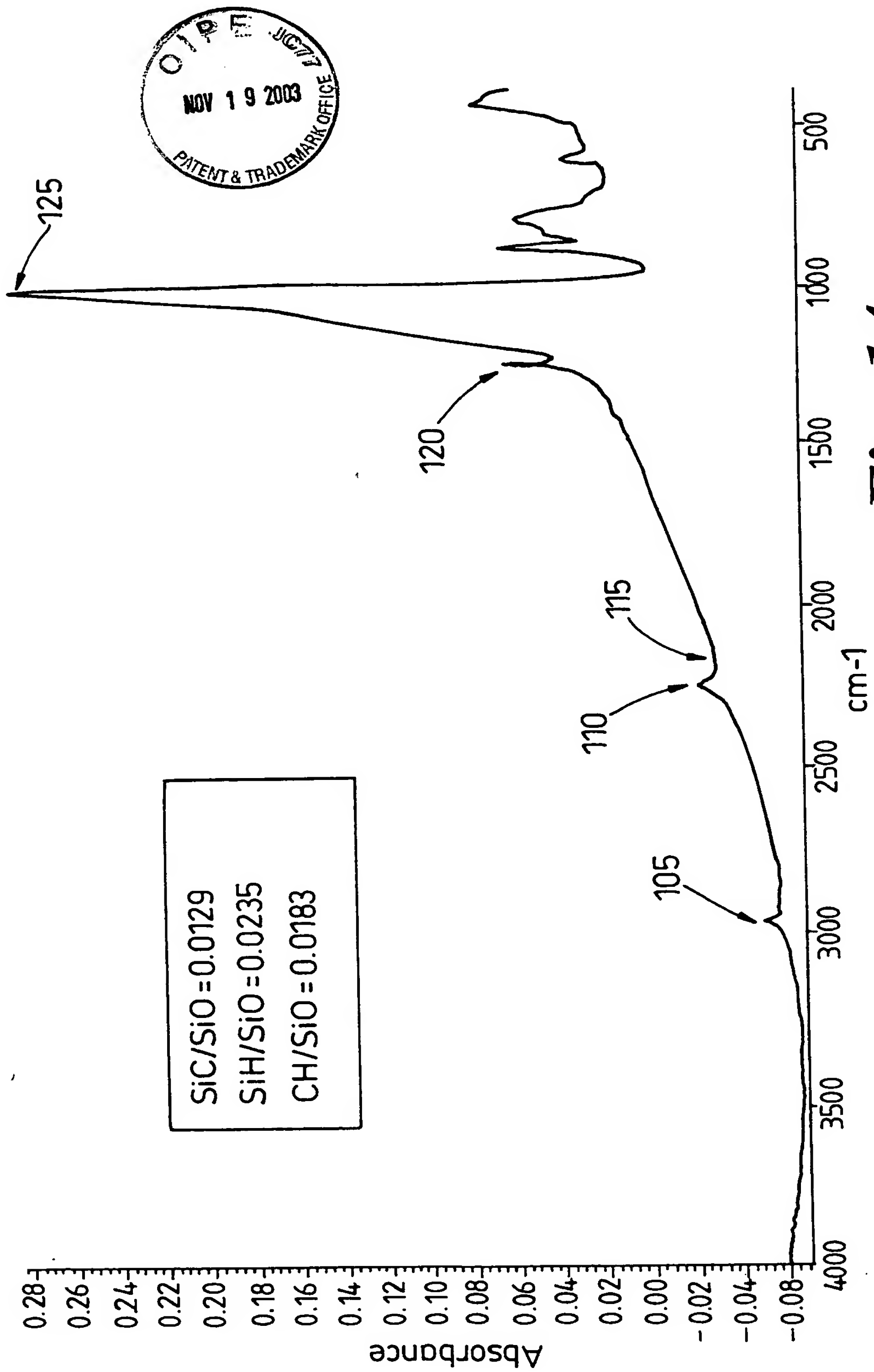


Fig 14

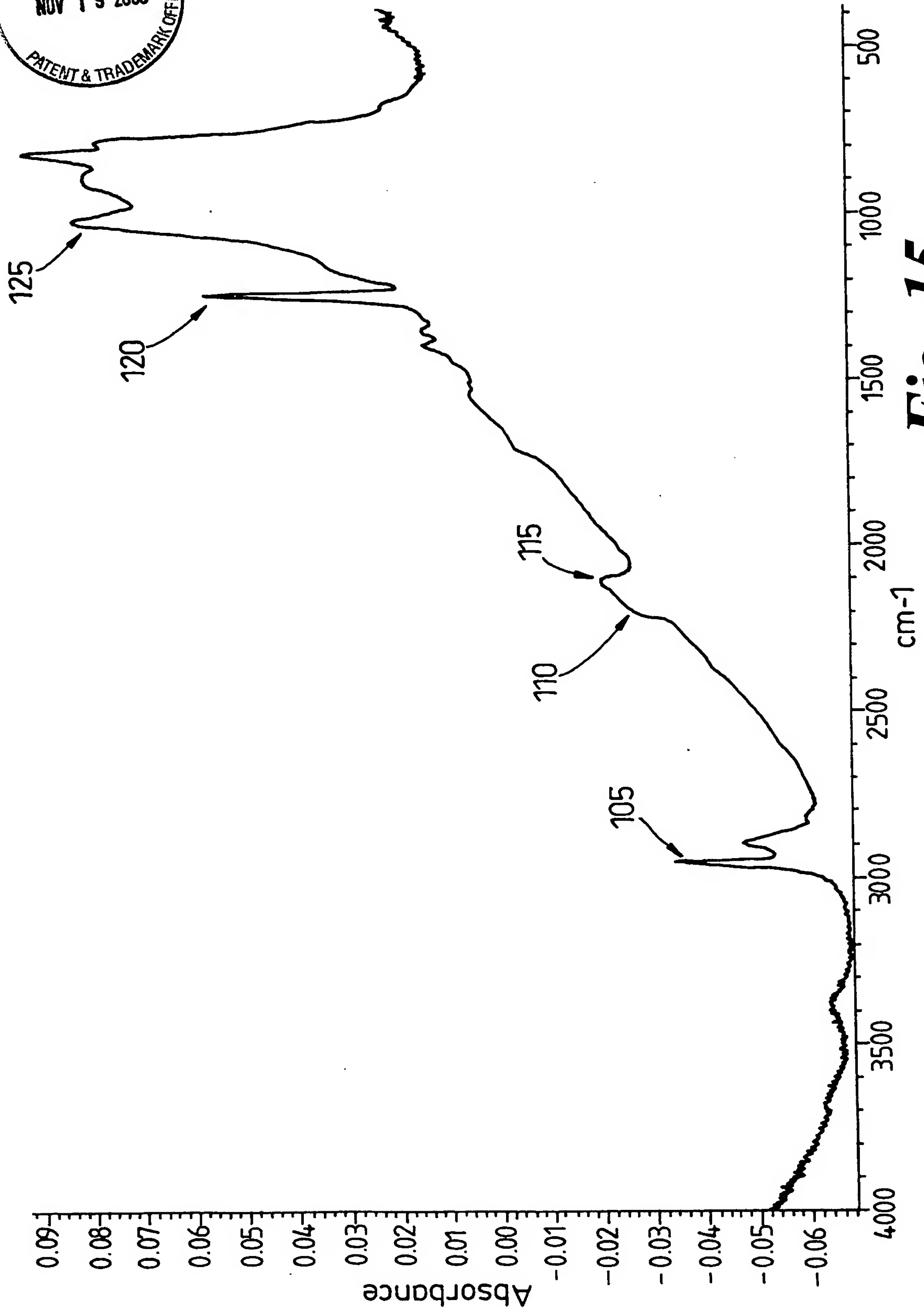


Fig. 15

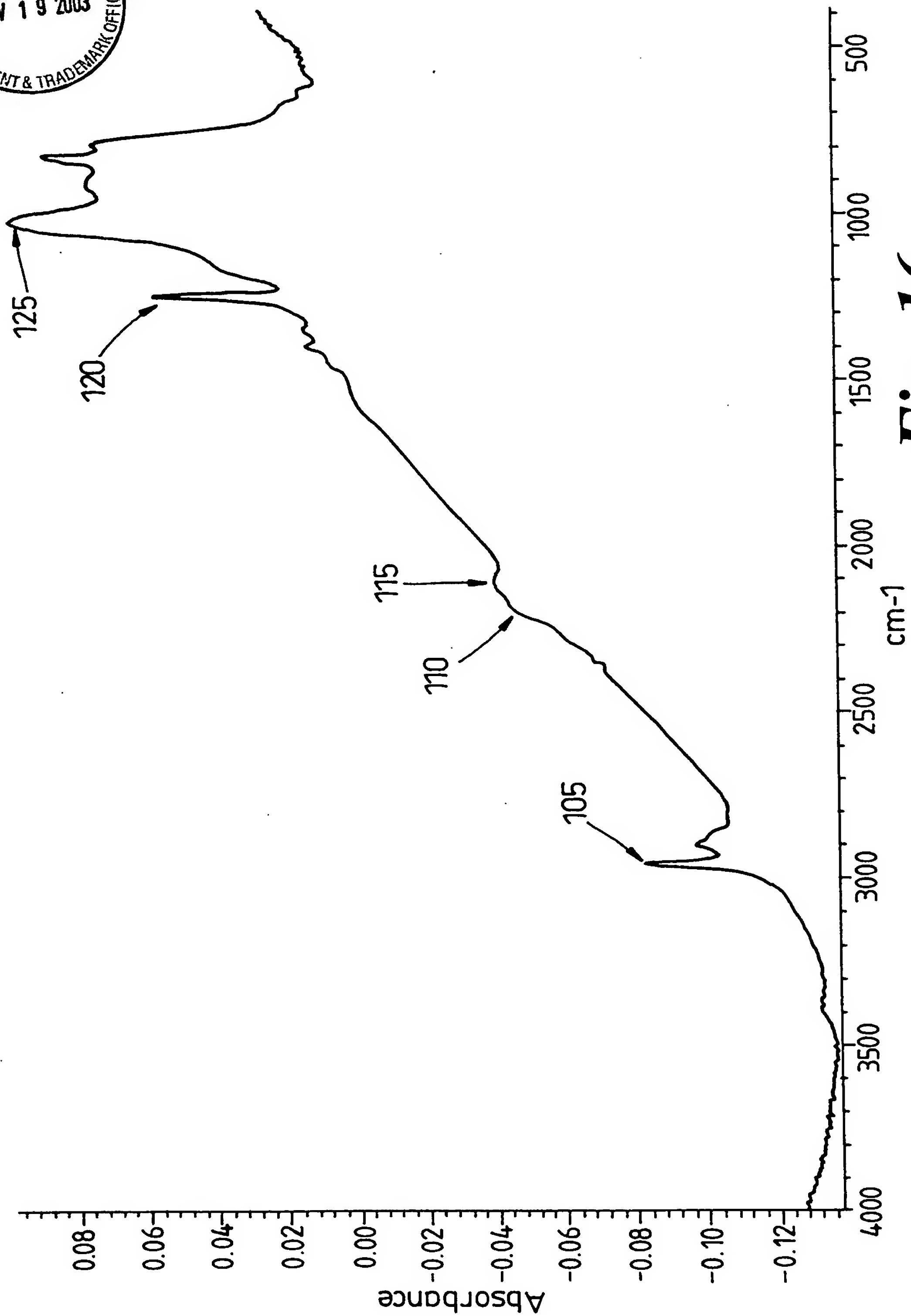


Fig. 16

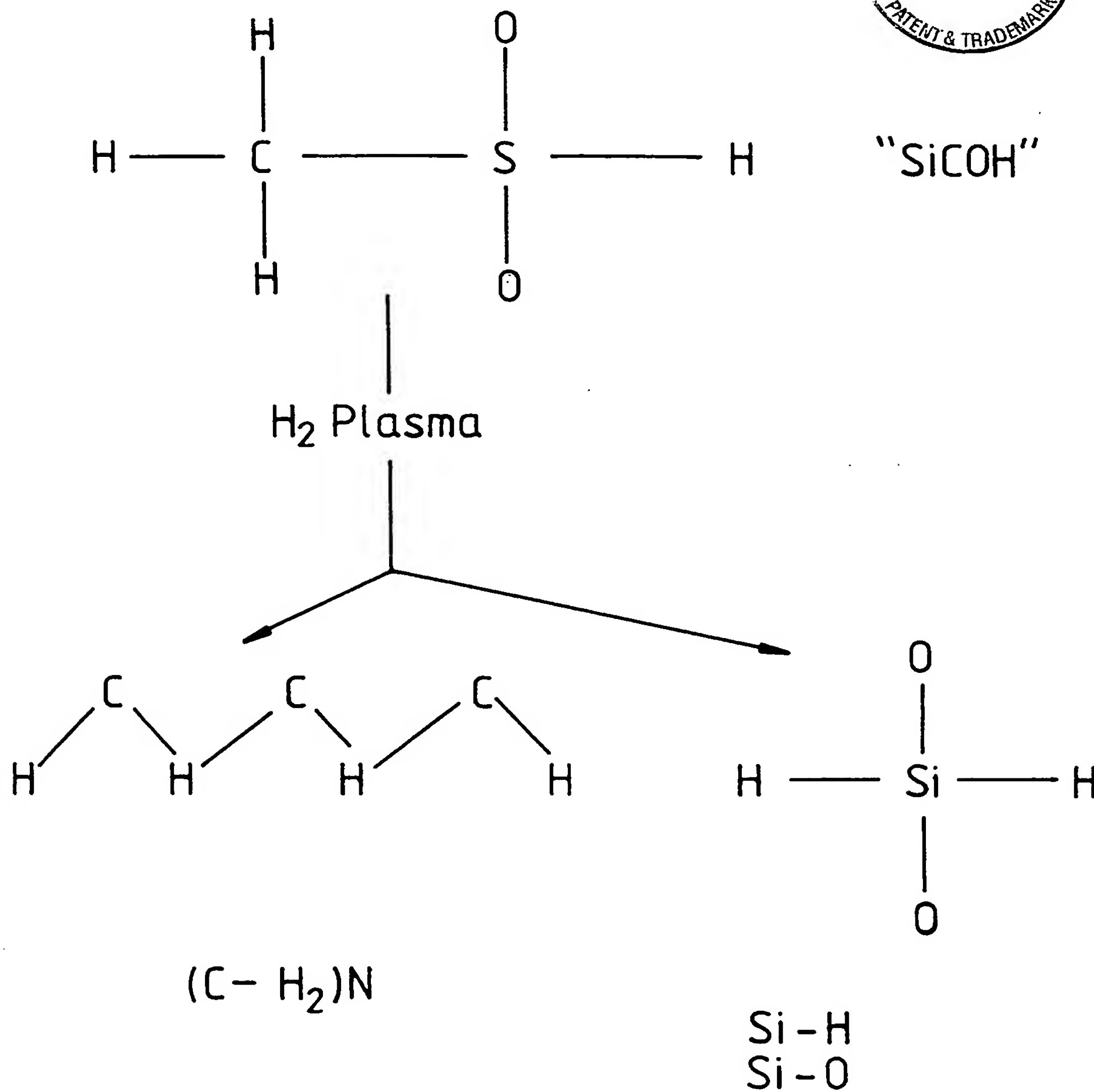


Fig. 17